Search Forms Hit List **Search Results** Help User Searches Clear D Bkwd Refs Generate Collection Fwd Refs Print Preferences Generate OACS Logout Search Results - Record(s) 1 through 11 of 11 returned. ☐ 1. Document ID: US 20030234404 A1 Using default format because multiple data bases are involved. Dec 25, 2003 File: PGPB L5: Entry 1 of 11 PGPUB-DOCUMENT-NUMBER: 20030234404 PGPUB-FILING-TYPE: new DOCUMENT-IDENTIFIER: US 20030234404 A1 TITLE: Semiconductor light-emitting device PUBLICATION-DATE: December 25, 2003 INVENTOR-INFORMATION: NAME CITY STATE COUNTRY RULE-47 Matsuoka, Takashi JP Kanagawa JP Okamoto, Hiroshi Kanagawa US-CL-CURRENT: 257/103; 257/88, 257/90, 257/94 Full Title Citation Front Review Classification Date Reference Sequences Attachments Claims KWIC Draw, De ☐ 2. Document ID: US 6709881 B2 L5: Entry 2 of 11 File: USPT Mar 23, 2004

US-PAT-NO: 6709881

DOCUMENT-IDENTIFIER: US 6709881 B2

TITLE: Method for manufacturing semiconductor and method for manufacturing

semiconductor device

Full | Title | Citation | Front | Review | Classification | Date | Reference | Sectleff est | Attachments | Claims | KMC | Draw De

☐ 3. Document ID: US 6642546 B2

L5: Entry 3 of 11

File: USPT

Nov 4, 2003

US-PAT-NO: 6642546

DOCUMENT-IDENTIFIER: US 6642546 B2

¶ TITLE: Nitride based semiconductor device and method of forming the same

Full Title Citation Front Review Classification Date Reference Sequences Attachments Claims KMC Draw De

4. Document ID: US 6610144 B2

L5: Entry 4 of 11

File: USPT

Aug 26, 2003

US-PAT-NO: 6610144

DOCUMENT-IDENTIFIER: US 6610144 B2

** See image for Certificate of Correction **

TITLE: Method to reduce the dislocation density in group III-nitride films

Full | Title | Citation | Front | Review | Classification | Date | Reference | Security | Attachinents | Claims | KMC | Draw De

5. Document ID: US 6586762 B2

L5: Entry 5 of 11

File: USPT

Jul 1, 2003

US-PAT-NO: 6586762

DOCUMENT-IDENTIFIER: US 6586762 B2

TITLE: Nitride semiconductor device with improved lifetime and high output power

Full | Title | Citation | Front | Review | Classification | Date | Reference | Sequences | Affactionents | Claims | KMC | Draw, De

☐ 6. Document ID: US 6558995 B1

L5: Entry 6 of 11

File: USPT

May 6, 2003

US-PAT-NO: 6558995

DOCUMENT-IDENTIFIER: US 6558995 B1

TITLE: Holographic, laser-induced fabrication of indium nitride quantum wires and quantum dots

quaricum docs

Full Title Citation Front Review Classification Date Reference Southences Attackments Claims KMC Draw De

☐ 7. Document ID: US 6555403 B1

L5: Entry 7 of 11

File: USPT

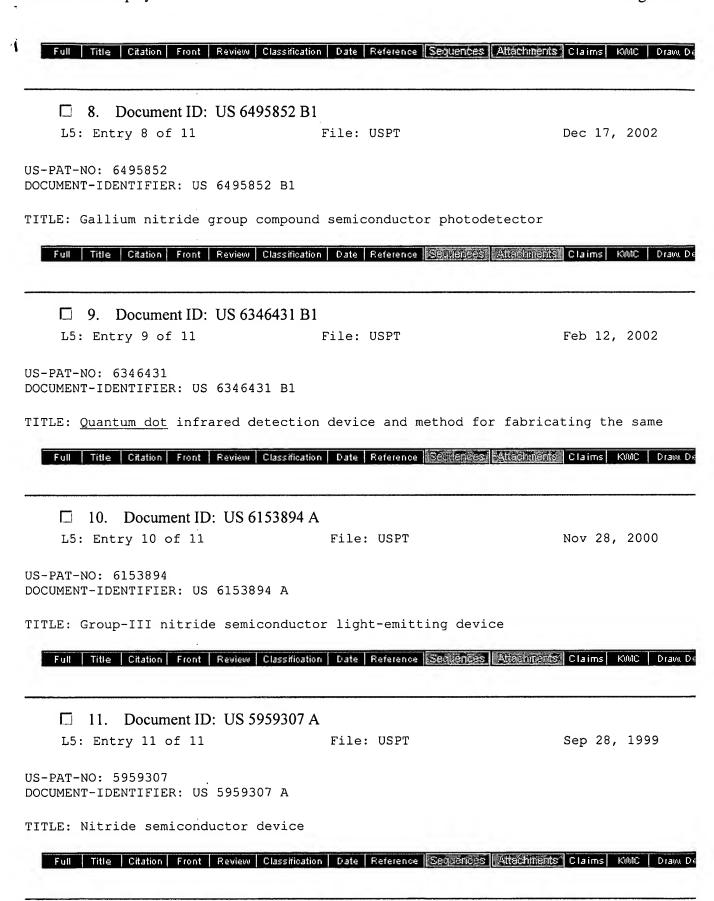
Apr 29, 2003

US-PAT-NO: 6555403

DOCUMENT-IDENTIFIER: US 6555403 B1

TITLE: Semiconductor laser, semiconductor light emitting device, and methods of manufacturing the same

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